

CPC5602C N Channel Depletion Mode FET



Features

- · Low on resistance 10 ohms
- · High input impedance
- · Low input and output leakage
- Small package size SOT-223
- PC Card (PCMCIA) Compatible
- PCB Space and Cost Savings

Applications

- Support Component for LITELINK ™
 Data Access Arrangement (DAA)
- Normally-on switch
- Telecom
- Constant Current Source

Description

The CPC5602C is an "N" channel depletion mode Field Effect Transistor (FET) that utilizes Clare's proprietary third generation vertical DMOS process. The third generation process realizes world class, high voltage MOSFET performance in an economical silicon gate process. The vertical DMOS process yields a highly reliable device particularly in difficult application environments such as telecommunications.

One of the primary applications for the CPC5602C is as a linear regulator/ hook switch for the LITELINK™ Data Access Arrangements (DAA) Devices (CPC5610A, CPC5611A, CPC5604A).

The CPC5602C has a typical on-resistance of 8Ω , a breakdown voltage exceeding 350V and is available in an SOT-223 package. As with all MOS devices, the FET structure prevents thermal runaway and thermal-induced secondary breakdown.

Absolute Maximum Ratings

| Parameter | Min | Max | Units |
|---------------------------|-----|------|-------|
| V _{DSS} Voltage | _ | 350 | V |
| Total Package Dissipation | _ | 2.5 | W |
| Operational Temperature | -40 | +85 | °C |
| Storage Temperature | -40 | +125 | οС |
| Soldering Temperature | _ | +220 | °C |

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this data sheet is not implied. Exposure of the device to the absolute maximum ratings for an extended period may degrade the device and effect its reliability.

Ordering Information

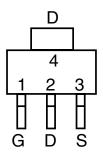
| Part # | Description |
|------------|------------------------------------|
| CPC5602C | N-Channel Depletion Mode FET, |
| | SOT-223 Package |
| CPC5602CTR | N-Channel Depletion Mode, SOT- |
| | 223 Package |
| | FET-TAPE and Reel (1000 units min) |



Electrical characteristics (@0 to 85°C unless otherwise specified)

| PARAMETERS | SYMBOL | MIN | TYP | MAX | UNITS | CONDITIONS |
|----------------------------|----------------------|------|-----|-----|-------|--|
| Breakdown Voltage | V _{(BR)DSS} | 350 | - | | V | V _{GS} =-5v, I _D <100μA |
| Gate-to-Source Off Voltage | V _{GS1} | -3.6 | | -2 | V | I _D =2uA, 10V <v<sub>DS<100V</v<sub> |
| Drain Current 1 | I _{D1} | - | - | 5 | mA | $V_{GS} = -2.7V, 5V < V_{DS} < 50V$ |
| Drain Current 2 | I _{D2} | 130 | - | - | mA | $V_{GS} = -0.57V, 5V < V_{DS} < 50V$ |
| Continuous Drain Current 1 | I _{DC1} | 125 | - | - | mA | V _{DS} =7V |
| Continuous Drain Current 2 | I _{DC2} | 60 | - | - | mA | V _{DS} =40V |
| On Resistance | R _{DS} | - | 8 | 10 | Ω | $V_{GS} = -0.35 \text{ V}, 0.1 \text{ V} < V_{DS} < 0.2 \text{ V}$ |
| Gate Leakage Current | I _{GSS} | - | - | .1 | μΑ | -10V <v<sub>GS<10V</v<sub> |
| Gate Capacitance | C _{ISS} | - | - | 300 | pF | $V_{DS} = V_{GS} = 0V$ |
| Thermal Resistance | O ^{JC} | - | - | 14 | °C/W | |

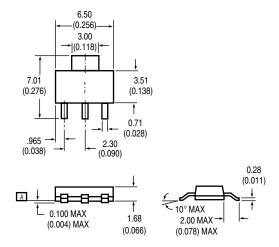
Package Pinout

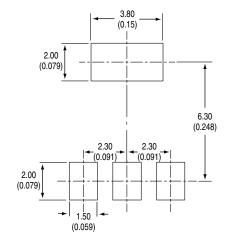


| Pin # | Name | | |
|-------|--------|--|--|
| 1 | GATE | | |
| 2 | DRAIN | | |
| 3 | SOURCE | | |
| 4 | DRAIN | | |



Mechanical Dimensions





Coplaner to A 0.08/(0.003) 4 PL.

Note: Values are typical except where noted.

Dimensions mm (inches)



CLARE LOCATIONS

Clare Headquarters 78 Cherry Hill Drive Beverly, MA 01915 Tel: 1-978-524-6700

Fax: 1-978-524-4900 Toll Free: 1-800-27-CLARE

Clare Micronix Division 145 Columbia Aliso Viejo, CA 92656-1490

Tel: 1-949-831-4622 Fax: 1-949-831-4628

SALES OFFICES

AMERICAS

Americas Headquarters

Clare

78 Cherry Hill Drive Beverly, MA 01915 Tel: 1-978-524-6700 Fax: 1-978-524-4900 Toll Free: 1-800-27-CLARE

Eastern Region

Clare

P.O. Box 856 Mahwah, NJ 07430 Tel: 1-201-236-0101 Fax: 1-201-236-8685 Toll Free: 1-800-27-CLARE

Central Region

Clare Canada Ltd. 3425 Harvester Road, Suite 202 Burlington, Ontario L7N 3N1 Tel: 1-905-333-9066

Fax: 1-905-333-1824

Western Region

Clare

1852 West 11th Street, #348

Tracy, CA 95376 Tel: 1-209-832-4367 Fax: 1-209-832-4732 Toll Free: 1-800-27-CLARE

Canada

Clare Canada Ltd. 3425 Harvester Road, Suite 202 Burlington, Ontario L7N 3N1

Tel: 1-905-333-9066 Fax: 1-905-333-1824

EUROPE

European Headquarters

CP Clare nv Bampslaan 17 B-3500 Hasselt (Belgium) Tel: 32-11-300868

France

Clare France Sales Lead Rep 99 route de Versailles 91160 Champlan

Fax: 32-11-300890

France

Tel: 33 1 69 79 93 50 Fax: 33 1 69 79 93 59

Germany

Clare Germany Sales ActiveComp Electronic GmbH Mitterstrasse 12 85077 Manching Germany

Tel: 49 8459 3214 10 Fax: 49 8459 3214 29

Italy

C.L.A.R.E.s.a.s. Via C. Colombo 10/A I-20066 Melzo (Milano) Tel: 39-02-95737160 Fax: 39-02-95738829

Sweden

Clare Sales Comptronic AB Box 167 S-16329 Spånga Tel: 46-862-10370

Tel: 46-862-10370 Fax: 46-862-10371

United Kingdom

Clare UK Sales Marco Polo House Cook Way Bindon Road Taunton UK-Somerset TA2 6BG

Tel: 44-1-823 352541 Fax: 44-1-823 352797

ASIA PACIFIC

Asian Headquarters

Clare

Room N1016, Chia-Hsin, Bldg II, 10F, No. 96, Sec. 2 Chung Shan North Road

Taipei, Taiwan R.O.C. Tel: 886-2-2523-6368 Fax: 886-2-2523-6369

http://www.clare.com

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